

Product data sheet

1. General description

Ultrafast power diode in a SOD113 (2-lead TO-220F) plastic package.

2. Features and benefits

- Fast switching
- Isolated plastic package
- Low leakage current
- Low forward voltage drop
- Low thermal resistance
- Soft recovery characteristic

3. Applications

- High frequency switched-mode power supplies
- Discontinuous Current Mode (DCM) Power Factor Correction (PFC)

4. Quick reference data

Table 1. Quick reference data	Table 1	I. Quick	reference	data
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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _R	reverse voltage	DC	-	-	600	V
I _{F(AV)}	average forward current	δ = 0.5 ; T _h ≤ 71 °C; square-wave pulse; <u>Fig. 1</u> ; Fig. 2; Fig. 3	-	-	10	A
I _{FSM} non-repetitive peak forward current	t_p = 10 ms; T _{j(init)} = 25 °C; sine-wave pulse; Fig. 4	-	-	80	A	
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	-	-	88	A
Static chara	octeristics					
V _F	forward voltage	I _F = 10 A; T _j = 25 °C; <u>Fig. 6</u>	-	1.5	2	V
		I _F = 10 A; T _j = 150 °C; <u>Fig. 6</u>	-	-	1.6	V
Dynamic ch	aracteristics					
t _{rr}	reverse recovery time	I_F = 1 A; V_R = 30 V; dI_F/dt = 50 A/µs; T _j = 25 °C; Fig. 7	-	35	50	ns

5. Pinning information

Table 2. F	Table 2. Pinning information									
Pin	Symbol	Description	Simplified outline	Graphic symbol						
1	К	cathode	mb	K A						
2	А	anode		001aaa020						
mb	n.c.	mounting base; isolated	TO-220F (SOD113)							

6. Ordering information

Table 3. Ordering information								
Type number	Package							
	Name	Description	Version					
BYV10X-600P	TO-220F	plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 2-lead TO-220 "full pack"	SOD113					

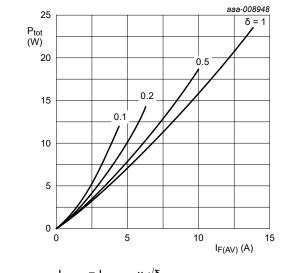
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7. Limiting values

Table 4. Limiting values

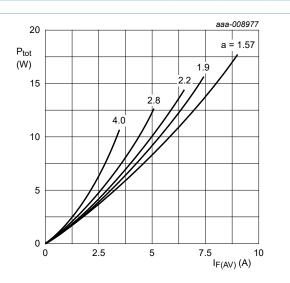
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{RRM}	repetitive peak reverse voltage		-	600	V
V _{RWM}	crest working reverse voltage		-	600	V
V _R	reverse voltage	DC	-	600	V
I _{F(AV)}	average forward current	δ = 0.5 ; T _h ≤ 71 °C; square-wave pulse; Fig. 1; Fig. 2; Fig. 3	-	10	A
I _{FRM}	repetitive peak forward current	δ = 0.5 $\ ; t_p$ = 25 µs; $T_h \leq \ 71 \ ^\circ C;$ squarewave pulse	-	20	A
I _{FSM}	non-repetitive peak forward current	t _p = 10 ms; T _{j(init)} = 25 °C; sine-wave pulse; <u>Fig. 4</u>	-	80	A
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	-	88	A
T _{stg}	storage temperature		-65	175	°C
Tj	junction temperature		-	175	°C



$$\begin{split} I_{F(AV)} &= I_{F(RMS)} \times \sqrt{\delta} \\ V_o &= 1.268 \; V; \; R_s = 0.031 \; \Omega \end{split}$$

Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values



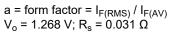
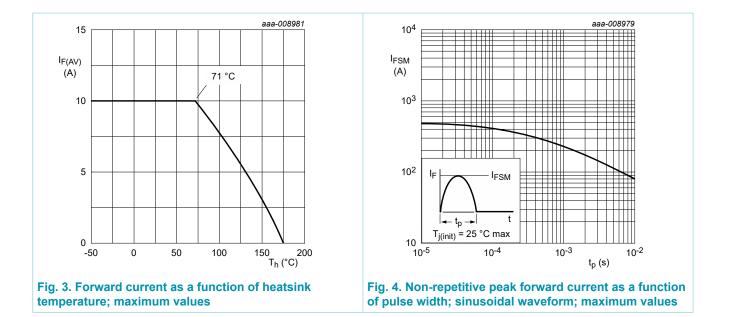


Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

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BYV10X-600P

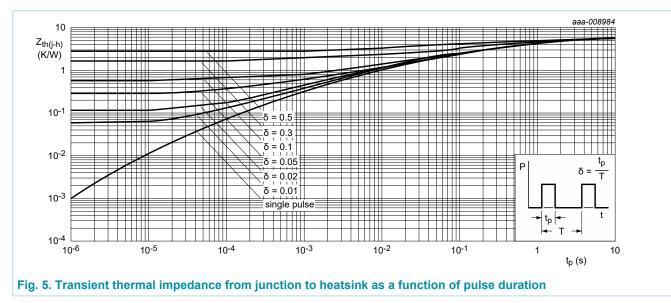
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8. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-h)}	thermal resistance	without heatsink compound	-	-	7.2	K/W
	from junction to heatsink	with heatsink compound; Fig. 5	-	-	5.5	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air	in free air	-	55	-	K/W



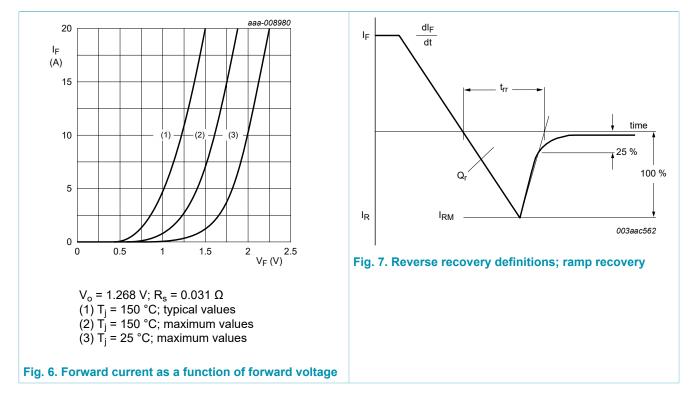
9. Isolation characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{isol(RMS)}	RMS isolation voltage	50 Hz \leq f \leq 60 Hz; RH \leq 65 %; from all pins to external heatsink; sinusoidal waveform; clean and dust free	-	-	2500	V
C _{isol}	isolation capacitance	from cathode to external heatsink	-	10	-	pF

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10. Characteristics

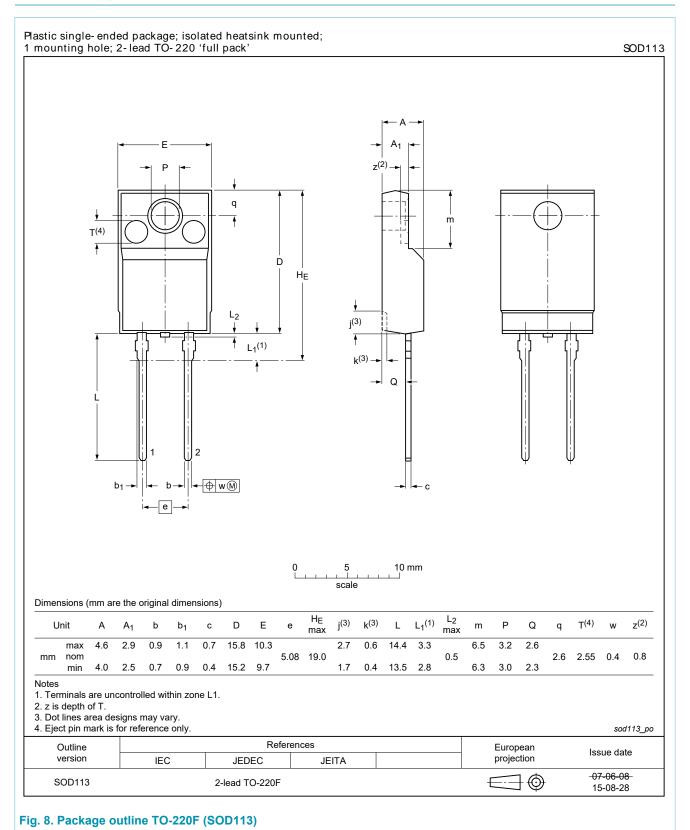
Table 7. Cha	racteristics						
Symbol	Parameter	Conditions	IV	lin	Тур	Max	Unit
Static chara	acteristics						,
V _F	forward voltage	I _F = 10 A; T _j = 25 °C; <u>Fig. 6</u>	-		1.5	2	V
		I _F = 10 A; T _j = 150 °C; <u>Fig. 6</u>	-		-	1.6	V
I _R	reverse current	V _R = 600 V; T _j = 25 °C	-		-	10	μA
		V _R = 500 V; T _j = 150 °C	-		-	250	μA
Dynamic ch	aracteristics						-,
t _{rr}	reverse recovery time	I_F = 1 A; V _R = 30 V; dI _F /dt = 50 A/µs; T _j = 25 °C; <u>Fig. 7</u>	-		35	50	ns
		I_F = 1 A; V _R = 30 V; dI _F /dt = 100 A/µs; T _j = 25 °C; <u>Fig. 7</u>	-		20	-	ns
		I_F = 10 A; V_R = 200 V; dI_F/dt = 200 A/ µs; T_j = 25 °C; <u>Fig. 7</u>	-		40	-	ns





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11. Package outline



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12. Legal information

Data sheet status

Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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